Diode Semiconductor Device - Page 1 of 1



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#### Inclosure Material:

Glass

# **Overall Length:**

Between 0.140 inches and 0.195 inches

# **Terminal Length:**

Between 0.090 inches and 1.300 inches

### **Overall Diameter:**

Between 0.135 inches and 0.185 inches

### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

26.4 breakdown voltage, dc

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector minor

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# Test Data Document:

81349-mil-s-19500/516 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

2 uninsulated wire lead

#### Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

# Fiig:

A110a0